SLG59M611V

Ultra-small 22 mΩ 4 A Load Switch with Reverse Current Blocking

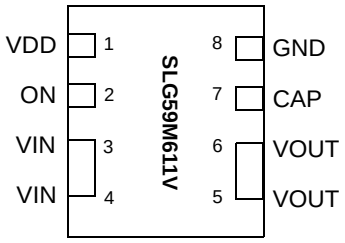
General Description

The SLG59M611V is a 22 mΩ 4 A single-channel load switch that is able to switch 1 to 5 V power rails. The product is packaged in an ultra-small 1.5 x 2.0 mm package.

Features

- 1.5 x 2.0 mm FC-TDFN 8L package (2 fused pins for drain and 2 fused pins for source)
- Logic level ON pin capable of supporting 0.85 V CMOS Logic
- User selectable ramp rate with external capacitor
- 22 mΩ RDS_{ON} while supporting 4 A
- Two Over Current Protection Modes
  - Short Circuit Current Limit
  - Active Current Limit
- Over Temperature Protection
- Pb-Free / Halogen-Free / RoHS compliant
- Operating Temperature: -40 °C to 85°C
- Operating Voltage: 2.5 V to 5.5 V

Pin Configuration

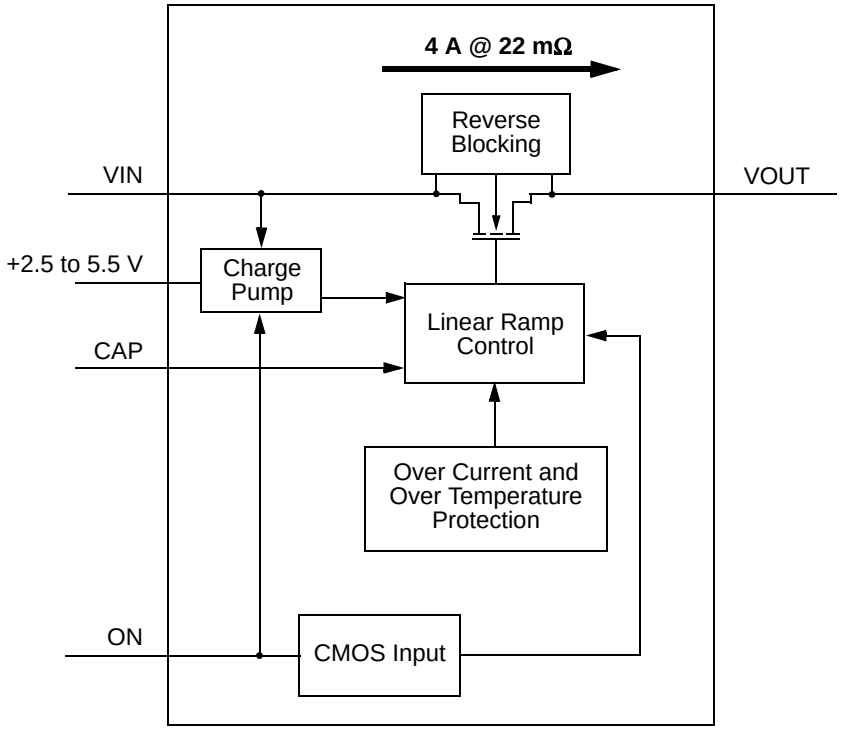


8-pin FC-TDFN
(Top View)

Applications

- Notebook Power Rail Switching
- Tablet Power Rail Switching
- Smartphone Power Rail Switching

Block Diagram



Pin Description

Pin #	Pin Name	Type	Pin Description
1	VDD	PWR	VDD power for load switch control (2.5 V to 5.5 V)
2	ON	Input	Turns MOSFET ON (4 MΩ pull down resistor) CMOS input with VIL < 0.3 V, VIH > 0.85 V
3	VIN	MOSFET	Drain of Power MOSFET (fused with pin 4)
4	VIN	MOSFET	Drain of Power MOSFET (fused with pin 3)
5	VOUT	MOSFET	Source of Power MOSFET (fused with pin 6)
6	VOUT	MOSFET	Source of Power MOSFET (fused with pin 5)
7	CAP	Input	Capacitor for controlling power rail ramp rate
8	GND	GND	Ground

Ordering Information

Part Number	Type	Production Flow
SLG59M611V	FC-TDFN 8L	Commercial, -40 °C to 85 °C
SLG59M611VTR	FC-TDFN 8L (Tape and Reel)	Commercial, -40 °C to 85 °C

Absolute Maximum Ratings

Parameter	Description	Conditions	Min.	Typ.	Max.	Unit
V_{DD}	Power Supply		--	--	7	V
T_S	Storage Temperature		-65	--	150	°C
ESD_{HBM}	ESD Protection	Human Body Model	2000	--	--	V
W_{DIS}	Package Power Dissipation		--	--	1	W
MOSFET IDS_{PK}	Peak Current from Drain to Source	For no more than 1 ms with 1% duty cycle	--	--	6	A

Note: Stresses greater than those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Electrical Characteristics

T_A = -40 °C to 85 °C (unless otherwise stated)

Parameter	Description	Conditions	Min.	Typ.	Max.	Unit
V_{DD}	Power Supply Voltage	-40 °C to 85 °C	2.5	--	5.5	V
I_{DD}	Power Supply Current (PIN 1)	when OFF	--	--	1	µA
		when ON, No load	--	70	100	µA
RDS_{ON}	Static Drain to Source ON Resistance	T_A 25°C @ 100 mA	--	22	28	mΩ
		T_A 70°C @ 100 mA	--	25	30	mΩ
		T_A 85°C @ 100 mA	--	27	31	mΩ
IDS	Operating Current	V_{IN} = 1.0 V to 5.5 V	--	--	4	A
V_{IN}	Drain Voltage		1.0	--	V_{DD}	V
T_{ON_Delay}	ON pin Delay Time	50% ON to Ramp Begin	0	300	500	µs
T_{Total_ON}	Total Turn On Time	50% ON to 90% V_{OUT}	Configurable [1]			ms
		Example: CAP (PIN 7) = 4 nF, V_{DD} = V_{IN} = 5 V, Source_Cap = 10 µF, IDS = 100 mA	--	1.96	--	ms
$T_{SLEWRATE}$	Slew Rate	10% V_{OUT} to 90% V_{OUT}	Configurable [1]			V/ms
		Example: CAP (PIN 7) = 4 nF, V_{DD} = V_{IN} = 5 V, Source_Cap = 10 µF, IDS = 100 mA	--	3.0	--	V/ms
$I_{REVERSE}$	Reverse Blocking Current	V_{OUT} = 5.0, V_{IN} = 0 V	--	1	--	µA
CAP_{SOURCE}	Source Cap	Source to GND	--	--	500	µF
ON_V_{IH}	High Input Voltage on ON pin		0.85	--	V_{DD}	V
ON_V_{IL}	Low Input Voltage on ON pin		-0.3	0	0.3	V
I_{LIMIT}	Active Current Limit	MOSFET will automatically limit current when V_{OUT} > 250 mV	--	6.0	--	A
	Short Circuit Current Limit	MOSFET will automatically limit current when V_{OUT} < 250 mV	--	0.5	--	A
$THERM_{ON}$	Thermal shutoff turn-on temperature		--	125	--	°C
$THERM_{OFF}$	Thermal shutoff turn-off temperature		--	100	--	°C
$THERM_{TIME}$	Thermal shutoff time		--	--	1	ms
T_{OFF_Delay}	OFF Delay Time	50% ON to V_{OUT} Fall, V_{DD} = V_{IN} = 5 V	--	7.5	15	µs

Notes:
1. Refer to table for configuration details.

SLG59M611V Turn ON

The normal power on sequence is first VDD, with VIN only being applied after VDD is > 1 V, and then ON after VIN is at least 90% of final value. The normal power off sequence is the power on sequence in reverse.

If VDD and VIN are turned on at the same time then it is possible that a voltage glitch will appear on VOUT before VDD achieves 1V which is the VT of the main MOSFET. The size of the glitch is dependent on source and drain capacitance loading and the ramp rate of VDD & VIN.

SLG59M611V Turn ON

The VOUT ramp follows a linear path, not an RC limitation provided the ramp is slow enough to not be current limited by load capacitance.

SLG59M611V Current Limiting

The SLG59M611V has two forms of current limiting.

Standard Current Limiting Mode

Current is measured by mirroring the current through the main MOSFET. The mirrored current is then sent through a resistor creating a voltage V(i) proportional to the MOSFET current. The V(i) is then compared with a Band Gap voltage V(BG). If V(i) exceeds the Band Gap voltage then the voltage V(g) on the gate of the main MOSFET is reduced. The V(g) continues to drop until V(i) < V(BG). This response is a closed loop response and is therefore very fast and current limits in less than a few micro-seconds. There is no difference between peak or constant current limit.

Temperature Cutoff

However, as the V(g) drops the Rds(ON) of the main MOSFET will increase, thus limiting the current, but also increasing the power dissipation of the IC. The IC is very small and cannot dissipate much power. Therefore, if a current limit condition is sustained the IC will heat up. If the temperature exceeds approximately 120°C, then V(g) will be brought low completely shutting off the main MOSFET. As the die cools the MOSFET will be turned back on at 100°C.

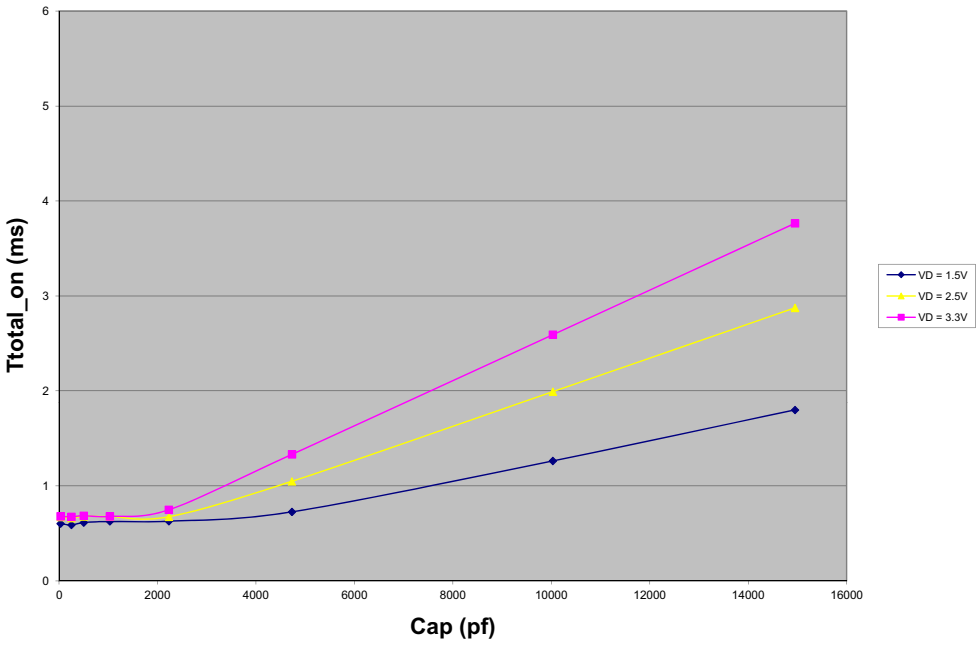
If the current limiting condition has not been mitigated then the die will again heat up to 120°C and the process will repeat.

Short Circuit Current Limiting Mode

When V(VOUT) < 250 mV, which is the case if there is a solder bridge during the manufacturing process or a hard short on the power rail, then the current is limited to approximately 500 mA. This current limit is accomplished in the same manner as the Standard Current Limiting Mode with the exception that the current mirror is 15x greater. Because the current mirror is so much larger, a 15x smaller main MOSFET current is required to generate the same V(i). If V(VOUT) rises above approximately 250 mV, then this mode is automatically switched out.

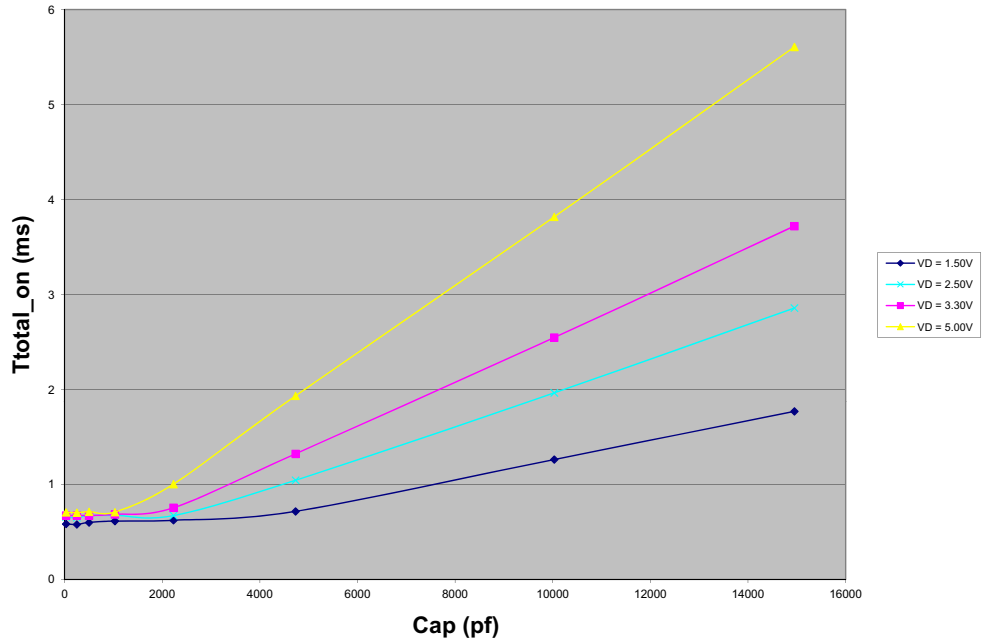
T_{Total_ON} vs. CAP @ V_{DD} = 3.3 V

SLG59M611V T_{Total_ON}: ON (50%) - V_{OUT} (90%)
V_{DD} = 3.3 V, T_A = 25 °C. C_L = 10 µF, IDS = 100 mA



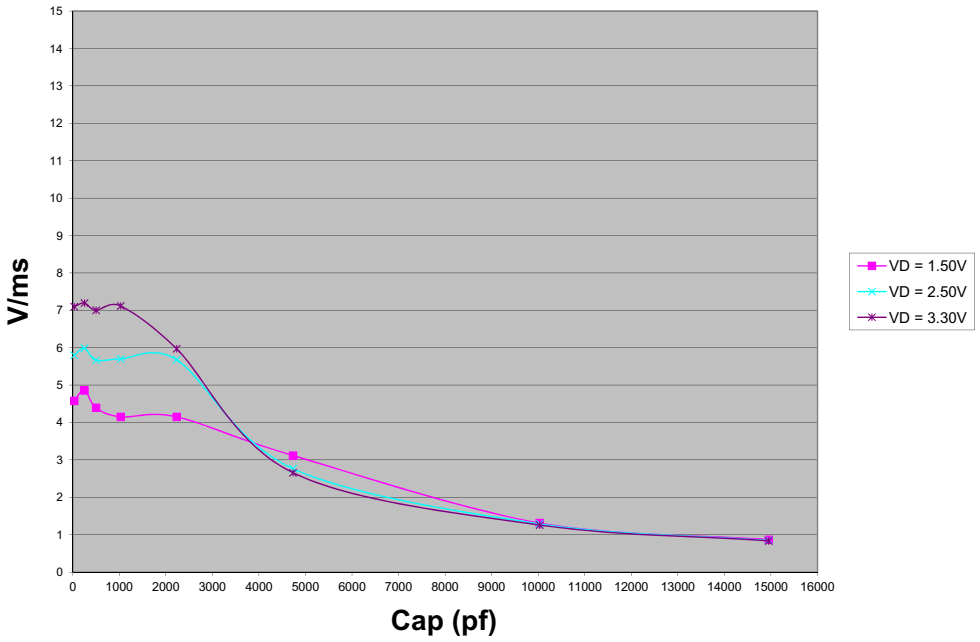
T_{Total_ON} vs. CAP @ V_{DD} = 5.0 V

SLG59M611V T_{Total_ON}: ON (50%) - V_{OUT} (90%)
V_{DD} = 5.0 V, T_A = 25 °C. C_L = 10 µF, IDS = 100 mA



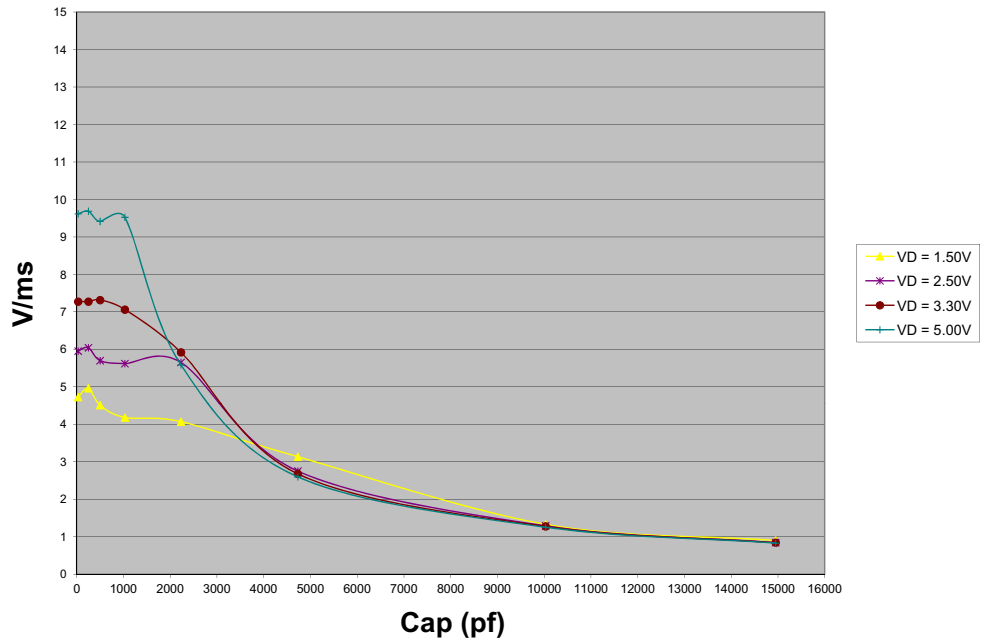
T_{SLEW} vs. CAP @ V_{DD} = 3.3 V

SLG59M611V T_{SLEW}: V_{OUT} (10%) - V_{OUT} (90%)
V_{DD} = 3.3 V, T_A = 25 °C. C_L = 10 µF, IDS = 100 mA

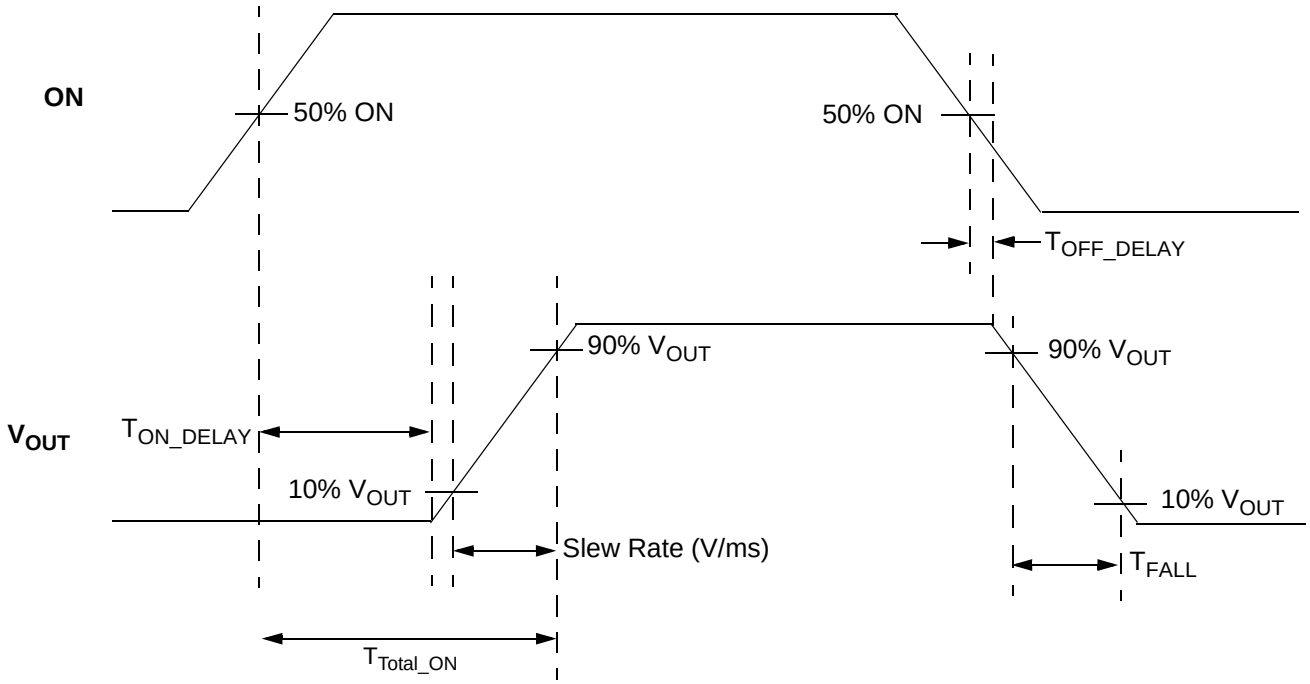


T_{SLEW} vs. CAP @ V_{DD} = 5.0 V

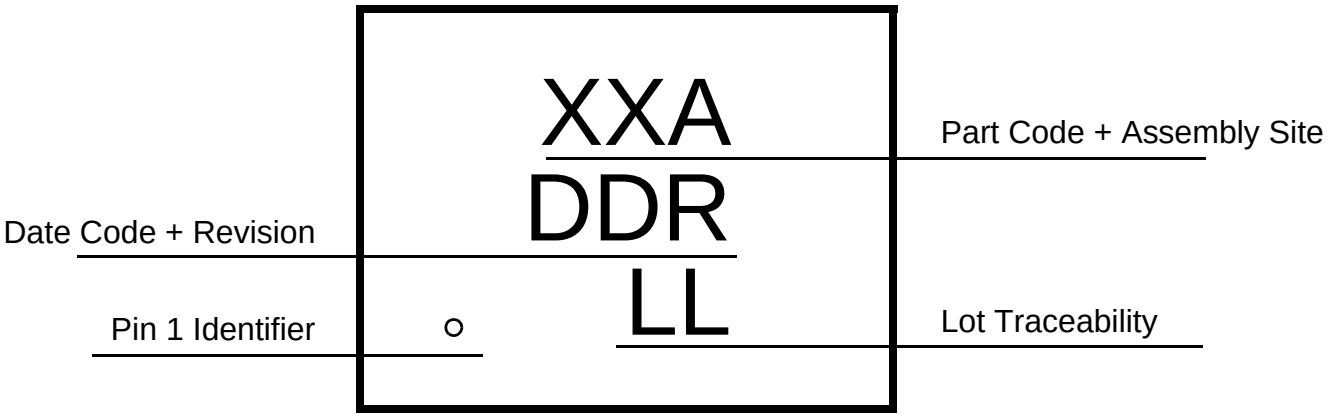
SLG59M611V T_{SLEW}: V_{OUT} (10%) - V_{OUT} (90%)
V_{DD} = 5.0 V, T_A = 25 °C. C_L = 10 µF, IDS = 100 mA



T_{Total_ON}, T_{ON_Delay} and Slew Rate Measurement

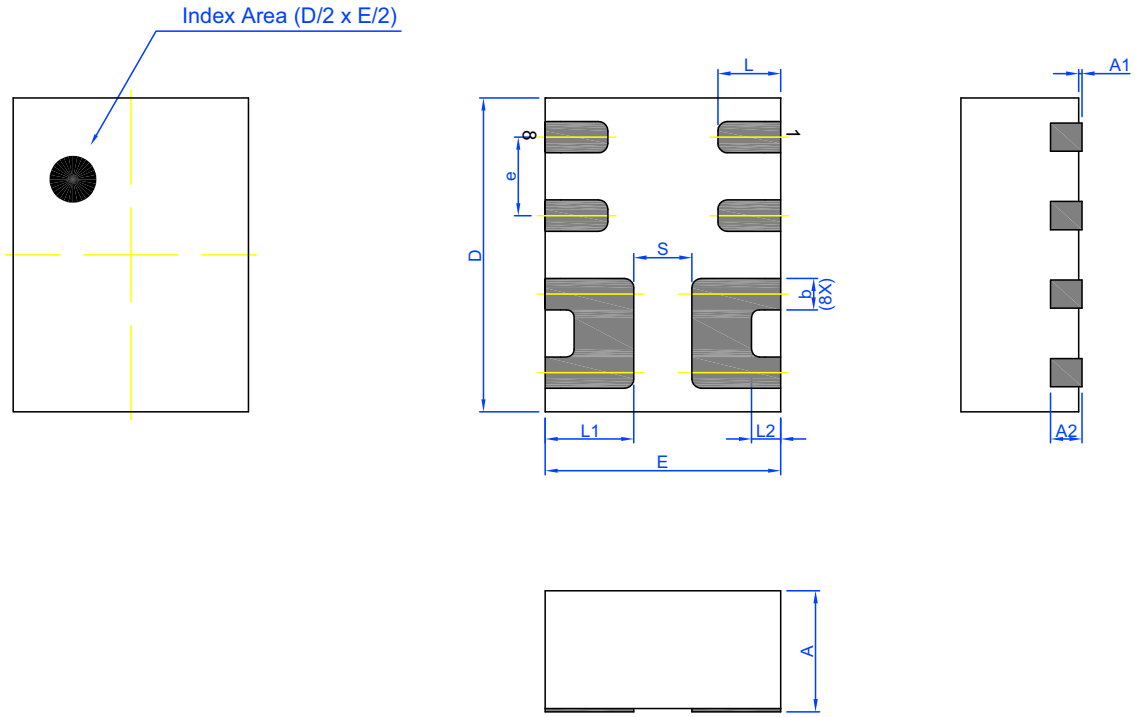


Package Top Marking System Definition



Package Drawing and Dimensions

8 Lead TDFN Package 1.5 x 2.0 mm (Fused Lead)
JEDEC MO-252, Variation W2015D



Unit: mm

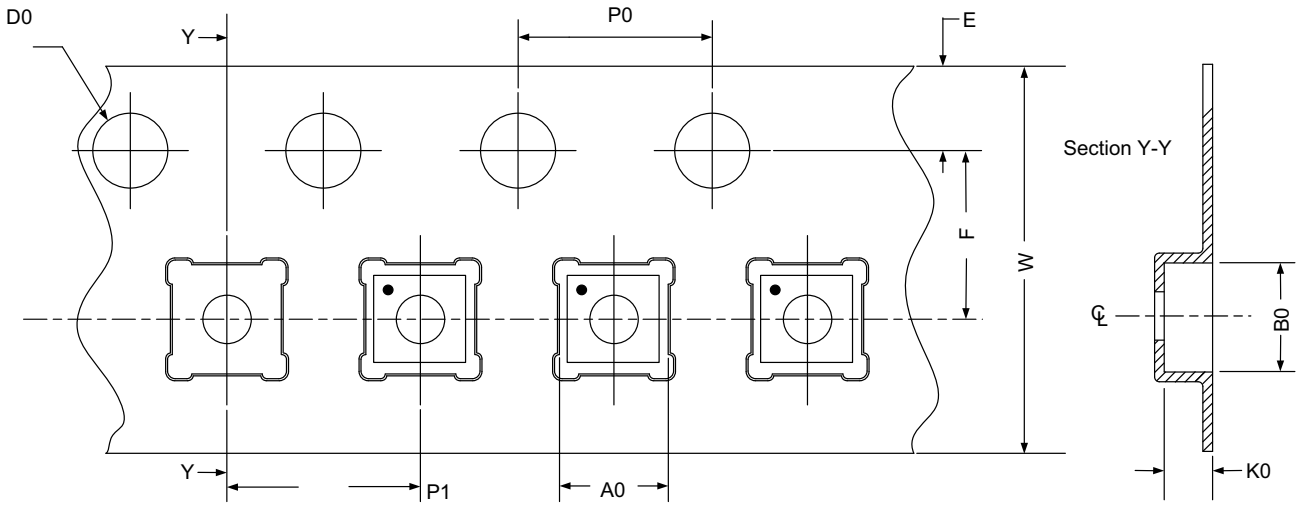
Symbol	Min	Nom.	Max	Symbol	Min	Nom.	Max
A	0.70	0.75	0.80	L	0.35	0.40	0.45
A1	0.005	-	0.060	L1	0.515	0.565	0.615
A2	0.15	0.20	0.25	L2	0.135	0.185	0.235
b	0.15	0.20	0.25	e	0.50 BSC		
D	1.95	2.00	2.05	S	0.37 REF		
E	1.45	1.50	1.55				

Tape and Reel Specifications

Package Type	# of Pins	Nominal Package Size [mm]	Max Units		Reel & Hub Size [mm]	Leader (min)		Trailer (min)		Tape Width [mm]	Part Pitch [mm]
			per Reel	per Box		Pockets	Length [mm]	Pockets	Length [mm]		
TDFN 8L FC Green	8	1.5 x 2.0 x 0.75	3000	3000	178 / 60	100	400	100	400	8	4

Carrier Tape Drawing and Dimensions

Package Type	Pocket BTM Length	Pocket BTM Width	Pocket Depth	Index Hole Pitch	Pocket Pitch	Index Hole Diameter	Index Hole to Tape Edge	Index Hole to Pocket Center	Tape Width
	A0	B0	K0	P0	P1	D0	E	F	W
TDFN 8L FC Green	1.68	2.18	0.9	4	4	1.5	1.75	3.5	8



Refer to EIA-481 specification

Recommended Reflow Soldering Profile

Please see IPC/JEDEC J-STD-020: latest revision for reflow profile based on package volume of 2.25 mm^3 (nominal). More information can be found at www.jedec.org.

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